

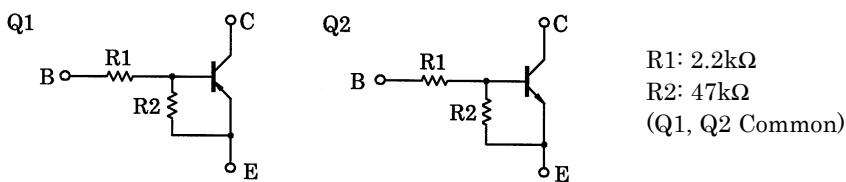
TOSHIBA Transistor
Silicon PNP Epitaxial Type (PCT Process) Silicon NPN Epitaxial Type (PCT Process)

RN4905

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- Including two devices in US6 (ultra super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process

Equivalent Circuit and Bias Resistor Values



Q1 Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	V_{CEO}	-50	V
Emitter-base voltage	V_{EBO}	-5	V
Collector current	I_C	-100	mA

Unit: mm

1. EMITTER 1 (E1)
 2. BASE 1 (B1)
 3. COLLECTOR 2 (C2)
 4. EMITTER 2 (E2)
 5. BASE 2 (B2)
 6. COLLECTOR 1 (C1)

US6

JEDEC —
 EIAJ —
 TOSHIBA 2-2J1A

Q2 Maximum Ratings (Ta = 25°C)

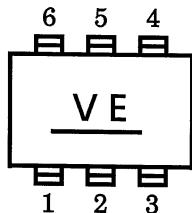
Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	50	V
Collector-emitter voltage	V_{CEO}	50	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_C	100	mA

Q1, Q2 Common Maximum Ratings ($T_a = 25^\circ\text{C}$)

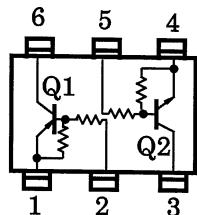
Characteristic	Symbol	Rating	Unit
Collector power dissipation	P_C *	200	mW
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55~150	$^\circ\text{C}$

* : Total rating

Marking



Equivalent Circuit (Top View)

Q1 Electrical Characteristics ($T_a = 25^\circ\text{C}$)

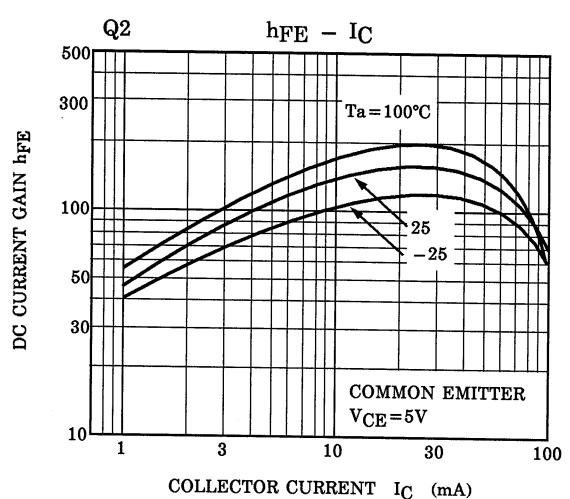
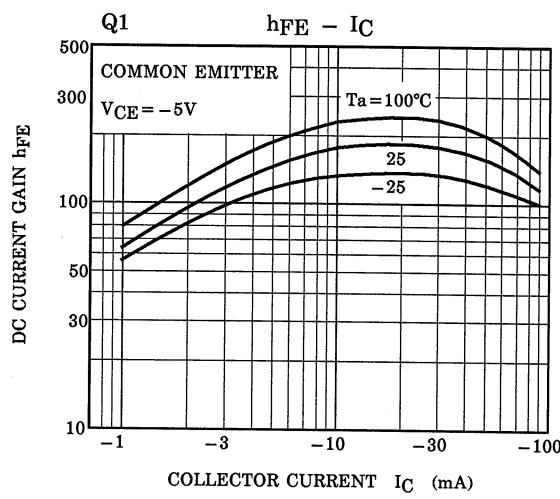
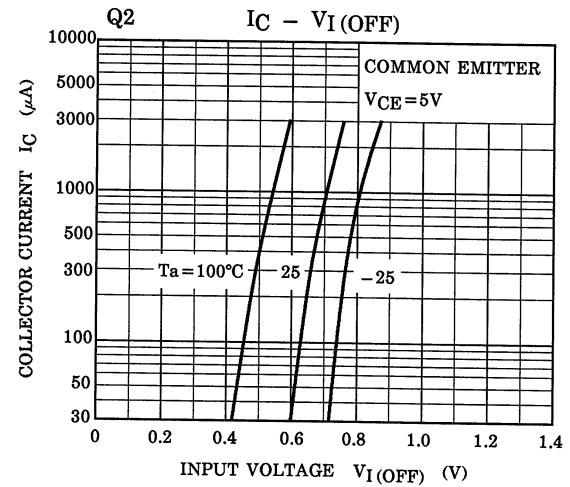
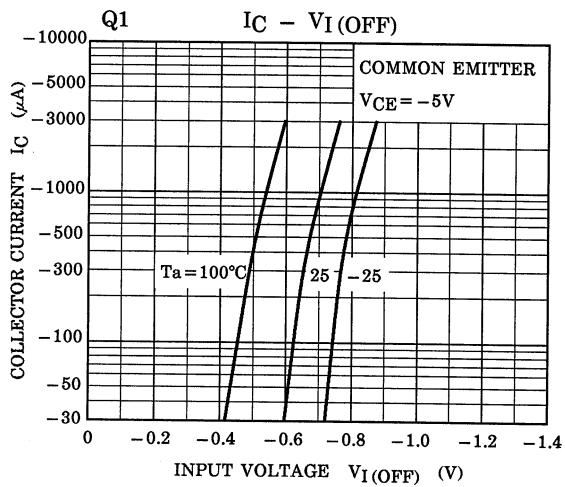
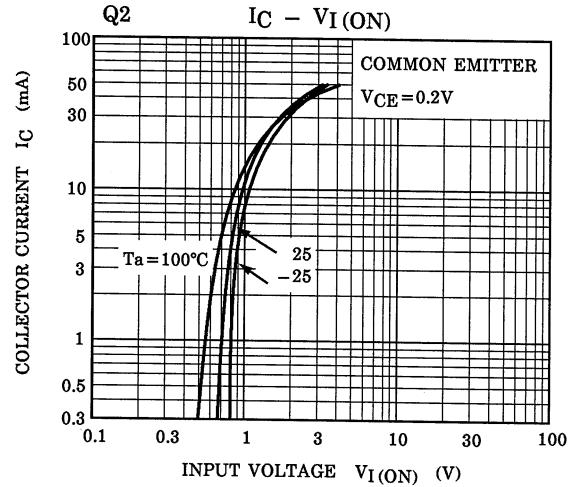
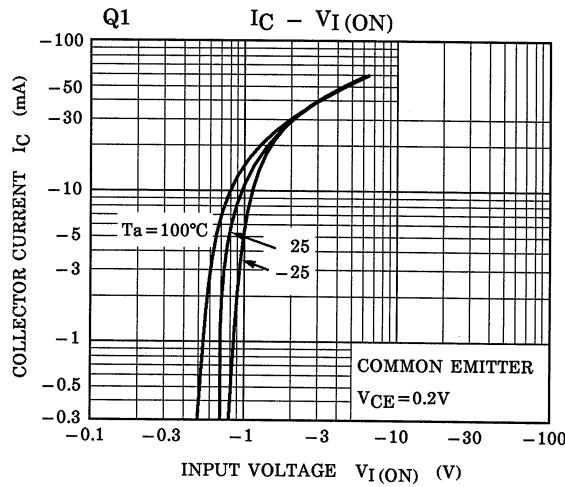
Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	—	$V_{\text{CB}} = -50\text{V}$, $I_E = 0$	—	—	-100	nA
	I_{CEO}	—	$V_{\text{CE}} = -50\text{V}$, $I_B = 0$	—	—	-500	
Emitter cut-off current	I_{EBO}	—	$V_{\text{EB}} = -5\text{V}$, $I_C = 0$	-0.078	—	-0.145	mA
DC current gain	h_{FE}	—	$V_{\text{CE}} = -5\text{V}$, $I_C = -10\text{mA}$	80	—	—	—
Collector-emitter saturation voltage	$V_{\text{CE}}(\text{sat})$	—	$I_C = -5\text{mA}$, $I_B = -0.25\text{mA}$	—	-0.1	-0.3	V
Input voltage (ON)	$V_I(\text{ON})$	—	$V_{\text{CE}} = -0.2\text{V}$, $I_C = -5\text{mA}$	-0.6	—	-1.1	V
Input voltage (OFF)	$V_I(\text{OFF})$	—	$V_{\text{CE}} = -5\text{V}$, $I_C = -0.1\text{mA}$	-0.5	—	-0.8	V
Transition frequency	f_T	—	$V_{\text{CE}} = -10\text{V}$, $I_C = -5\text{mA}$	—	200	—	MHz
Collector output capacitance	C_{ob}	—	$V_{\text{CB}} = -10\text{V}$, $I_E = 0$	—	3	6	pF

Q2 Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I _{CBO}	—	V _{CB} = 50V, I _E = 0	—	—	100	nA
	I _{CEO}	—	V _{CE} = 50V, I _B = 0	—	—	500	
Emitter cut-off current	I _{EBO}	—	V _{EB} = 5V, I _C = 0	0.078	—	0.145	mA
DC current gain	h _{FE}	—	V _{CE} = 5V, I _C = 10mA	80	—	—	—
Collector-emitter saturation voltage	V _{CE} (sat)	—	I _C = 5mA, I _B = 0.25mA	—	0.1	0.3	V
Input voltage (ON)	V _I (ON)	—	V _{CE} = 0.2V, I _C = 5mA	0.6	—	1.1	V
Input voltage (OFF)	V _I (OFF)	—	V _{CE} = 5V, I _C = 0.1mA	0.5	—	0.8	V
Transition frequency	f _T	—	V _{CE} = 10V, I _C = 5mA	—	250	—	MHz
Collector output capacitance	C _{ob}	—	V _{CB} = 10V, I _E = 0, f = 1 MHz	—	3	6	pF

Q1, Q2 Common Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Input resistor	R ₁	—	—	1.54	2.2	2.86	kΩ
Resistor ratio	R ₁ /R ₂	—	—	0.0421	0.0468	0.0515	—



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